3.18.03

500.41080X00

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

pplicants:

MORIYA et al.

Serial No.:

10/043,099

Filed:

January 14, 2002

For:

SEMICONDUCTOR DEVICE AND ITS PRODUCTION

PROCESS

Group:

2814

Examiner:

S. Rao

AMENDMENT

Assistant Commissioner for Patents Washington, D.C. 20231

March 10, 2003

Sir:

In response to the Office Action dated October 8, 2002, the period of response for which extension is requested by the attached Petition for Extension of Time, please amend the above-identified application as follows:

In the Claims:

Please cancel claims 1-11 without prejudice.

Please add new claims 17-24 as follows:

17. A semiconductor device comprising:

a semiconductor substrate;

gate insulators formed on said substrate, and

gate electrodes formed on said gate insulators,

wherein said gate insulators are comprised of a material as a main component